
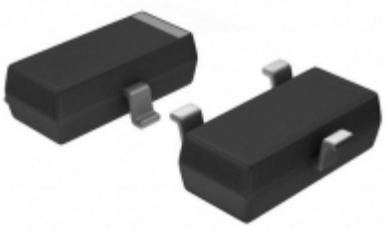
	<p>SI2372DS-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI2372DS-T1-GE3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CHAN 30V SOT23</p> <p>Datenblätter:  SI2372DS-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 60818 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2372DS-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CHAN 30V SOT23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	60818 pcs Stock
detaillierte Beschreibung	N-Channel 30V 4A (Ta), 5.3A (Tc) 960mW (Ta), 1.7W
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	960mW (Ta), 1.7W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4A (Ta), 5.3A (Tc)
Rds On (Max) @ Id, Vgs	33 mOhm @ 3A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8.9nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	288pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI2372DS-T1-GE3TR

SI2372DS-T1-GE3 ist neu im Original, Suche SI2372DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2372DS-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI2372DS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2377DS-T1-E3 AOS AOS SOT-23</p>	 <p>SI2371EDS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 4.8A SOT-23</p>	 <p>SI2372DS AOS SI2372DS AOS</p>	 <p>SI2374DS-T1-GE3 Vishay / Siliconix MOSFET N-CHAN 20V SOT23</p>
 <p>SI2374DS-T1-E3 VISHAY VISHAY SOT23</p>	 <p>SI2372DS-T1-E3 VISHAY SI2372DS-T1-E3 VISHAY</p>	 <p>SI2372DS-T1-GE3 Vishay / Siliconix MOSFET N-CHAN 30V SOT23</p>	 <p>SI2374DS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 20V SOT23</p>

heiße Teile

Mehr

SI2343DS-T1-GE3	SI2344DS-E3	SI2347DS-T1-GE3	SI2347DS-T1-GE3	SI2351DS-T1-E3
SI2351DS-T1-E3	SI2351DS-T1-GE3	SI2351DS-T1-GE3	SI2356DS-T1-GE3	SI2356DS-T1-GE3
SI2365EDS	SI2365EDS-T1-GE3	SI2365EDS-T1-GE3	SI2366DS-T1-E3	SI2366DS-T1-GE
SI2366DS-T1-GE3	SI2366DS-T1-GE3	SI2367DS-T1-E3	SI2367DS-T1-GE3	SI2367DS-T1-GE3
SI2369DS-T1-GE3	SI2369DS-T1-GE3	SI2371EDS-T1-GE3	SI2371EDS-T1-GE3	SI2372DS-T1-E3
SI2372DS-T1-GE3	SI2374DS-T1-GE3	SI2374DS-T1-GE3	SI2377DS-T1-GE3	SI2377EDS
SI2377EDS-T1-E3	SI2377EDS-T1-GE3	SI2377EDS-T1-GE3	SI2392ADS-T1-E3	SI2392ADS-T1-GE3
SI2392ADS-T1-GE3	SI2392DS-T1-GE3	SI2392DS-T1-GE3	SI2399CDS-T1-GE3	SI2399DS-T1-GE3
SI2399DS-T1-GE3	SI2400-BS	SI2400-FS	SI2400-FSR	SI2400-KS
SI2400-KSR	SI2401-FS	SI2401-FSR	SI2401-FSR.	SI2401-KS

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